

L Number	Hits	Search Text	DB	Time stamp
-	10	((("5999308") or ("5990850") or ("6064511") or ("5335240") or ("5998298"))).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/17 17:47
-	647	photonic and semiconductor and substrate and stack\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/15 18:35
-	643	photonic and semiconductor and substrate and stack\$4	USPAT; US-PGPUB	2003/04/15 14:41
-	4	photonic and semiconductor and substrate and stack\$4	EPO; JPO; DERWENT; IBM_TDB	2003/04/15 14:41
-	406	photonic and semiconductor and substrate and stack\$4 and dielectric and material	USPAT; US-PGPUB	2003/04/15 14:43
-	27	359/321 and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/15 18:41
-	49	359/344 and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/15 18:46
-	9	359/585 and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/15 18:46
-	16	359/586 and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/15 18:47
-	9	359/587 and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/15 18:48
-	13	359/588 and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/15 18:48
-	7	343/911R and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/24 14:17
-	93	372/43 and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/15 19:59
-	176	372/45 and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/24 14:17
-	0	372/451 and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/15 21:24

-	98	385/131 and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/15 21:34
-	10	385/13 and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/15 21:35
-	62	385/132 and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/24 14:17
-	5	438/690,697.ccls. and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/24 14:24
-	2	("5937118").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/15 21:41
-	74	(first near3 dielectric) and (second near3 dielectric) and (photonic adj (crystal\$4 or band\$1gap\$2))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/17 17:50
-	67	(first near2 dielectric) and (second near2 dielectric) and (photonic adj (crystal\$4 or band\$1gap\$2))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/17 17:50
-	45	(first near1 dielectric) and (second near1 dielectric) and (photonic adj (crystal\$4 or band\$1gap\$2))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/17 18:04
-	2	(first near3 dielectric) and (second near3 dielectric) and (photonic adj (crystal\$4 or band\$1gap\$2)) and (semiconductor near substrate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/17 18:25
-	15	257/21 and (photonic adj (bandgap or band-gap or crystal\$1))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/17 18:06
-	69	430/\$.ccls. and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/24 14:21
-	5	430/\$.ccls. and photonic.ti.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/24 12:28
-	1	((430/\$).CCLS. AND PHOTONIC AND SEMICONDUCTOR AND SUBSTRATE) and 6274293.PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/24 12:29
-	1165	photonic.ti.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/24 12:45

-	138	photonic.ti. and forming and etching	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/24 12:45
-	128	photonic.ti. and forming and etching	USPAT; US-PGPUB	2003/04/24 12:46
-	64	photonic.ti. and forming and etching and Photonic near (crystal or bandgap)	USPAT; US-PGPUB	2003/04/24 12:47
-	0	343/900 and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/24 14:37
-	115	372/43,45.ccls. and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/01 10:25
-	7	438/694 and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/24 14:24
-	58	257/21 and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/24 14:26
-	71	359/322,245,250,321,327,238,226,332,248.ccls and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/24 15:19
-	71	359/322,245,250,321,327,238,226,332,248.ccls and photonic and semiconductor and	USPAT; US-PGPUB	2003/04/24 15:16
-	2086	phbstonate and semiconductor and substrate	USPAT; US-PGPUB	2003/04/24 14:43
-	2	343/786,772.ccls. and photonic and semiconductor and substrate	USPAT; US-PGPUB	2003/04/24 15:17
-	72	359/322,245,250,321,237,238,226,332,248.ccls and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/24 15:20
-	98	372/44,45.ccls. and photonic and semiconductor and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/01 10:26
-	1	("5739796").PN.	USPAT	2004/04/18 19:45
-	6	((("5999308") or ("5990850") or ("6064511") or ("5335240") or ("5998298") or ("6521136"))).PN.	USPAT	2004/04/18 20:01
-	0	359/321,245,250,332,238,344,585,586,587,588 and photonic.dclm.	USPAT	2004/04/18 20:03
-	34	359/321,245,250,332,238,344,585,586,587,588 and photonic.ti.	USPAT	2004/04/18 20:04
-	3	("3654809" "5740287" "6262830").PN.	USPAT	2004/04/18 20:31
-	35	359/321,245,250,332,238,344,585,586,587,588 and photonic.ab.	USPAT	2004/04/18 20:40
-	75	359/321,245,250,332,238,344,585,586,587,588 and photonic.bsum.	USPAT	2004/04/18 20:39
-	34	359/321,245,250,332,238,344,585,586,587,588 and photonic.clm.	USPAT	2004/04/18 20:41
-	2465	photonic.ab.	EPO; JPO; DERWENT; IBM_TDB	2004/04/18 20:52
-	611	photonic.clm.	USPAT	2004/04/18 20:42
-	502	photonic.ab.	USPAT	2004/04/18 20:42
-	2168	photonic.bsum.	USPAT	2004/04/18 20:42

-	342	photonic.clm. and photonic.ab. and photonic.bsum.	USPAT	2004/04/18 20:42
-	211	(photonic.clm. and photonic.ab. and photonic.bsum.) and photonic.ti.	USPAT	2004/04/18 20:43
-	1435	photonic.ti.	EPO; JPO; DERWENT; IBM_TDB	2004/04/18 20:52
-	635	photonic.ti. and crystal	EPO; JPO; DERWENT; IBM_TDB	2004/04/18 20:53
-	86	photonic.ti. and crystal and dielectric	EPO; JPO; DERWENT; IBM_TDB	2004/04/18 20:53
-	263	photonic and semiconductor and (plurality near2 layer\$1)	USPAT	2004/05/19 19:00
-	140	photonic and semiconductor and (plurality near1 layer\$1)	USPAT	2004/05/19 19:00
-	91	photonic.bsum. and semiconductor and (plurality near1 layer\$1)	USPAT	2004/05/19 19:19
-	0	KOSCIELNIAK.in. and WACLAW and c.	USPAT	2004/05/19 19:20
-	0	KOSCIELNIAK.in. and WACLAW and c.	US-PGPUB	2004/05/19 19:20
-	0	KOSCIELNIAK.in. and WACLAW	US-PGPUB	2004/05/19 19:21
-	1	KOSCIELNIAK.in. and WACLAW	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/19 19:21